

BYT3400B(-TR)

FAST RECOVERY RECTIFIER DIODE

MAIN PRODUCT CHARACTERISTICS

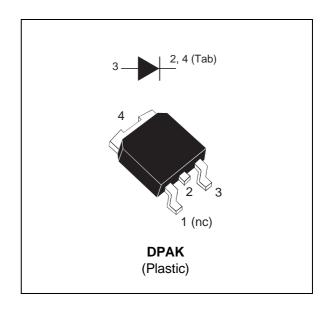
lF(AV)	3 A
V _{RRM}	400 V
V _F (max)	1.4 V

FEATURES AND BENEFITS

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING
- SURFACE MOUNT PACKAGE
- TAPE AND REEL OPTION:-TR

DESCRIPTION

Single high voltage rectifier suited to Switch Mode Power Supplies and other power converters.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	400	V
I _{F(RMS)}	RMS forward current	10	Α
I _{F(AV)}	Average forward current	3	Α
I _{FSM}	Surge non repetitive forward current	60	Α
Tstg	Storage temperature range	- 40 to + 150	°C
Tj	Maximum junction temperature	150	°C

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{TH} (j-c)	Junction to case	TBD	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Tests Conditions	Tests Conditions		Min.	Тур.	Max.	Unit
I _R *	Reverse leakage current	Tj = 25°C	$V_R = V_{RRM}$			20	μΑ
		Tj = 100°C				0.5	mA
V _F **	Forward voltage drop	Tj = 25°C	I _F = 3 A			1.5	V
		Tj = 100°C	I _F = 3 A			1.4	

Pulse test : * tp = 5 ms, δ < 2 %

** tp = 380 μ s, δ < 2%

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RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Тур.	Max.	Unit
trr	Tj = 25℃	IF = 0.5A I _R = 1A	Irr = 0.25A			25	ns
		$I_F = 1A$ $V_R = 30V$	$dI_F/dt = -15 A/\mu s$			60	ns

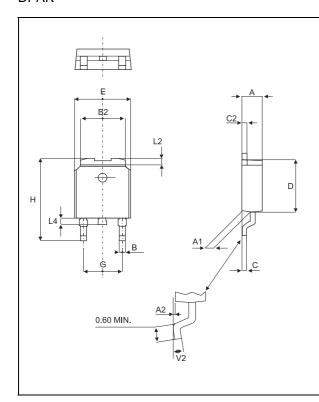
TURN-OFF SWITCHING CHARACTERISTICS

Symbol	ool Test Conditions			Min.	Тур.	Max.	Unit
t _{IRM}	Vcc = 200V	$I_F = 3A$	Lp ≤ 0.05μH		35	50	ns
I _{RM}	Tj = 100℃	dl _F /dt = -50 A/μs			1.5	2	A

To evaluate the maximum conduction losses use the following equation : P = 1.1 x IF(AV) + 0.08 $\:$ IF 2 (RMS)

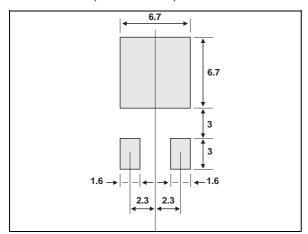
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PACKAGE MECHANICAL DATA DPAK



	DIMENSIONS				
REF.	Millimeters		Inc	hes	
	Min.	Max	Min.	Max.	
Α	2.20	2.40	0.086	0.094	
A1	0.90	1.10	0.035	0.043	
A2	0.03	0.23	0.001	0.009	
В	0.64	0.90	0.025	0.035	
B2	5.20	5.40	0.204	0.212	
С	0.45	0.60	0.017	0.023	
C2	0.48	0.60	0.018	0.023	
D	6.00	6.20	0.236	0.244	
Е	6.40	6.60	0.251	0.259	
G	4.40	4.60	0.173	0.181	
Н	9.35	10.10	0.368	0.397	
L2	0.80 typ.		0.03	1 typ.	
L4	0.60	1.00	0.023	0.039	
V2	0°	8°	0°	8°	

FOOT PRINT (in millimeters)



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